Abstract Submitted for the MAR17 Meeting of The American Physical Society

MegaOhm extraordinary Hall effect in oxidized CoFeB¹ GRE-GORY KOPNOV, ALEXANDER GERBER, Tel Aviv University — We report on the development of controllably oxidized CoFeB ferromagnetic films demonstrating the extraordinary Hall effect (EHE) resistivity exceeding 1 Ω cm and magnetic field sensitivity up to 10⁶ Ω/T . Such EHE resistivity is four orders of magnitude higher than that previously observed in ferromagnetic materials, while sensitivity is two orders larger than the best of semiconductors.

 $^1\mathrm{This}$ research was supported in part by TAU Nano- Center Grant No. 060328561.

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Date submitted: 13 Nov 2016

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